

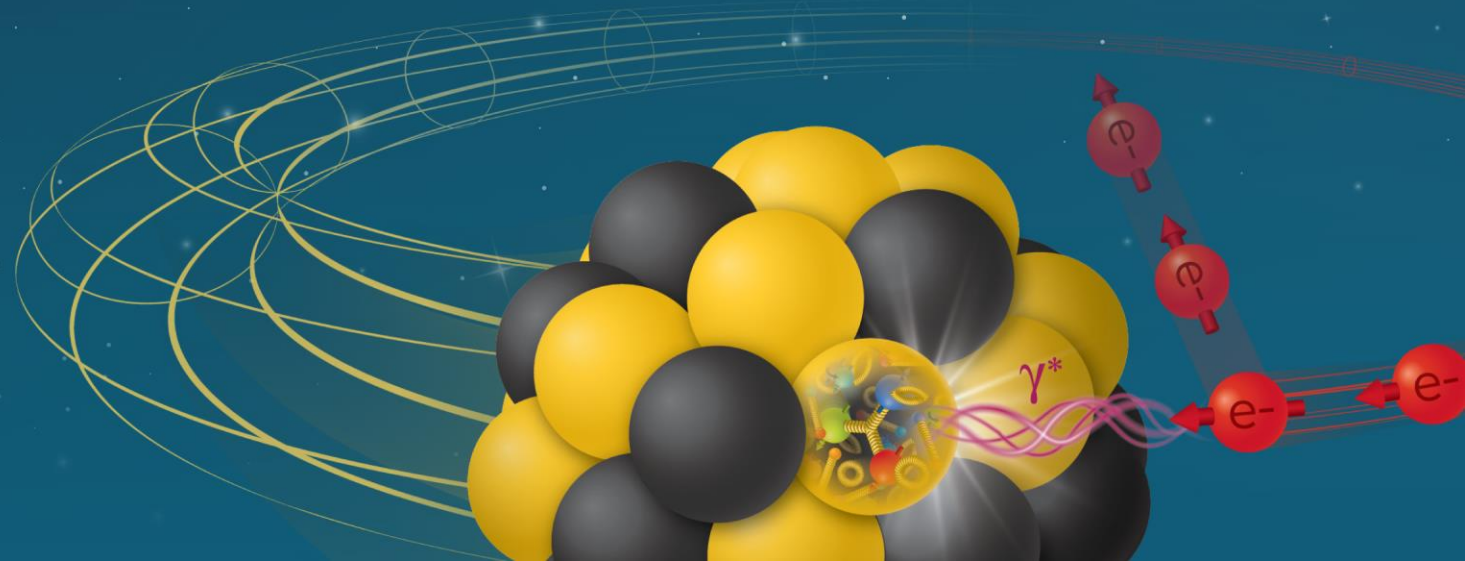
Beam-Beam Simulation Models and Numerical Noises for Flat Beam Collisions in the EIC

Yun Luo

Electron-Ion Collider Directorate
Brookhaven National Laboratory

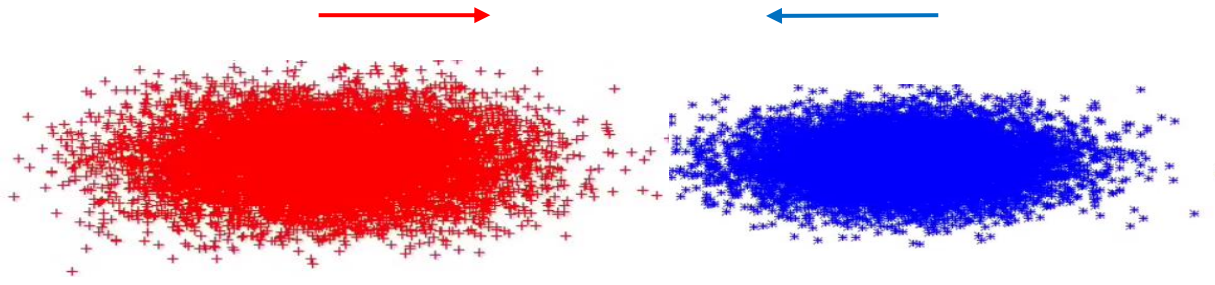
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Electron-Ion Collider



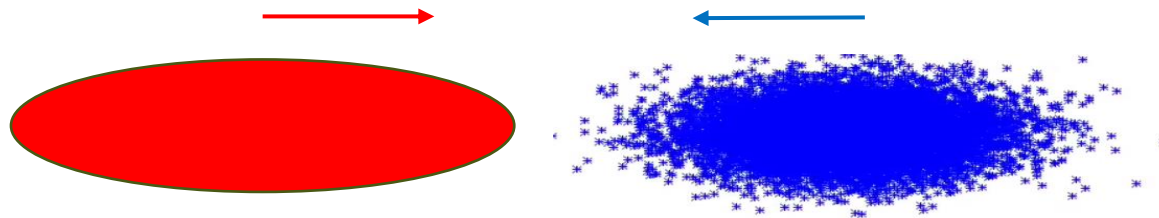
Numerical Simulation Models for the EIC

- **Strong-strong simulation model**



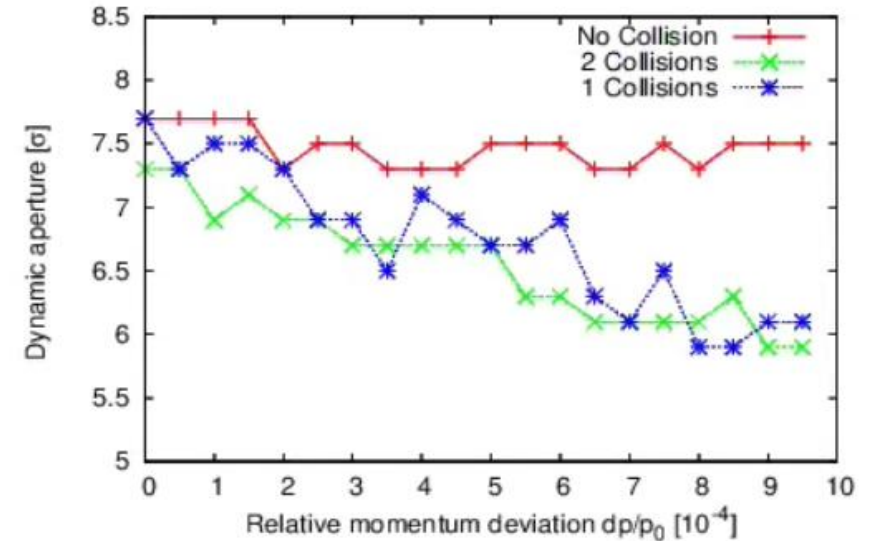
Both bunches are represented by ~ a million macro-particles. Subject to numerical noises.

- **Weak-Strong simulation model**



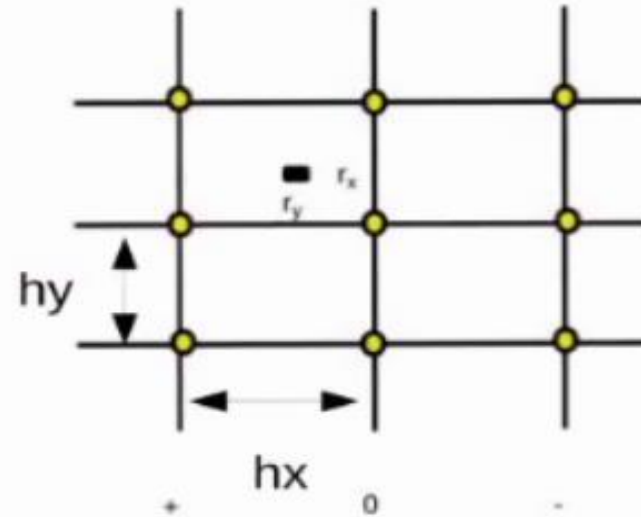
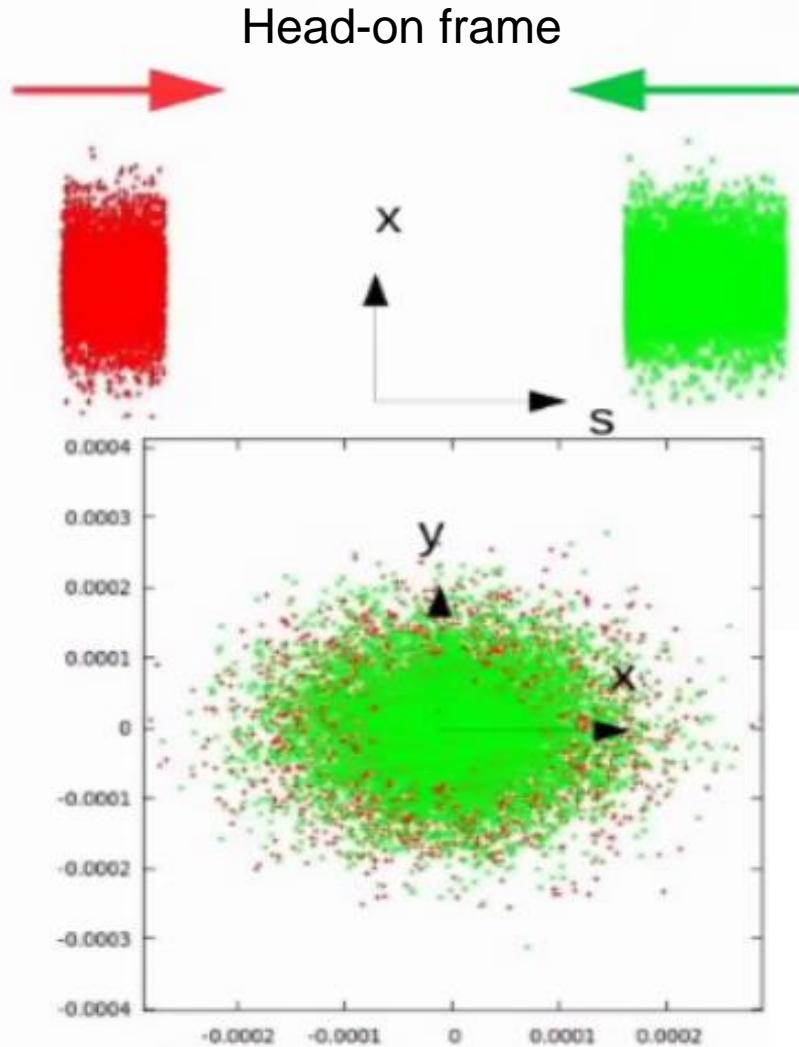
Strong bunch is rigid while weak bunch is represented by macro-particles. Not consistent.

- **Dynamic aperture calculation**



- Importance of long-term proton stability is crucial for the EIC beam-beam interaction simulation studies.

Strong-Strong Model (Particle-In-Cell, Poisson Solver)



+ **Triangular-Shaped Cloud (TSA)** technique used to distribute particle charge onto 256 * 256 mesh points.

- **Poisson's Equation** (FFT method)

$$\left(\frac{\partial^2}{\partial x^2} + \frac{\partial^2}{\partial y^2} \right) \phi(x, y) = -2\pi \rho_c(x, y)$$

$$\vec{E} = -\nabla \phi \quad \mathbf{B} = \vec{\beta} \times \mathbf{E}/c$$

Flatness Scan Study: Strong-Strong Model

Flatness is defined as σ_y^* / σ_x^* at IP

Calculated with BBSS

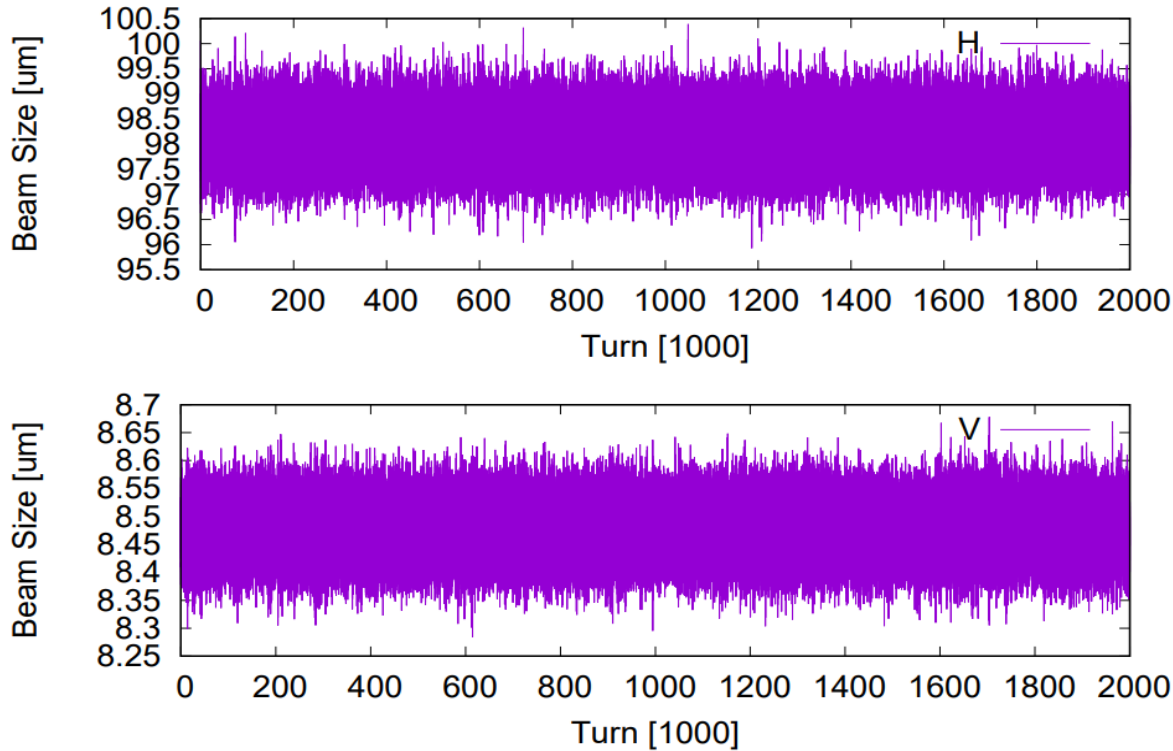
flatness	ID	emitx_p nm	emity_p nm	betx*_p cm	bety*_p cm	emitx_e nm	emity_e nm	betx*_e cm	bety*_e cm		lumi 1e34	proton Hsize growth rate	proton Vsize growth rate
0.06	88	11.9	0.7	90	5.4	20	0.64	63	4.0		1.2	1000%/h	2400%/h
0.08	86	11.7	0.9	90	7.2	20	0.90	65	5.7		0.98	900%/h	1700%/h
0.09	104	11.3	1.0	90	8.1	20	1.1	62	6.0		0.91	800%/h	1500%/h
0.10	78	11.0	1.1	90	9.0	20	1.4	59	6.9		0.83	800%/h	1100%/h
0.11	54	10.9	1.2	90	10.0	20	1.6	59	7.7		0.78	1100%/h	1100%/h
0.12	44	10.9	1.3	90	10.9	20	1.7	60	8.4		0.71	900%/h	1000%/h
0.14	99	9.9	1.4	90	12.6	20	1.9	60	9.6		0.66	900%/h	1200%/h
0.09	118	11.3	1.0	80	7.2	20	1.1	55	5.6		1.0	700%/h	1400%/h



In strong-strong simulation, half million macro-particles used and tracked to 50k turns. We linearly fit beam sizes between 25k to 50k turns (5-10 electron SR damping periods) to get a rough growth rate in unit of %/hour (extrapolated from 25k turns).

Growth Rates vs Flatness: Weak-Strong Model

An example with flatness 0.09



Calculated with SimTrack

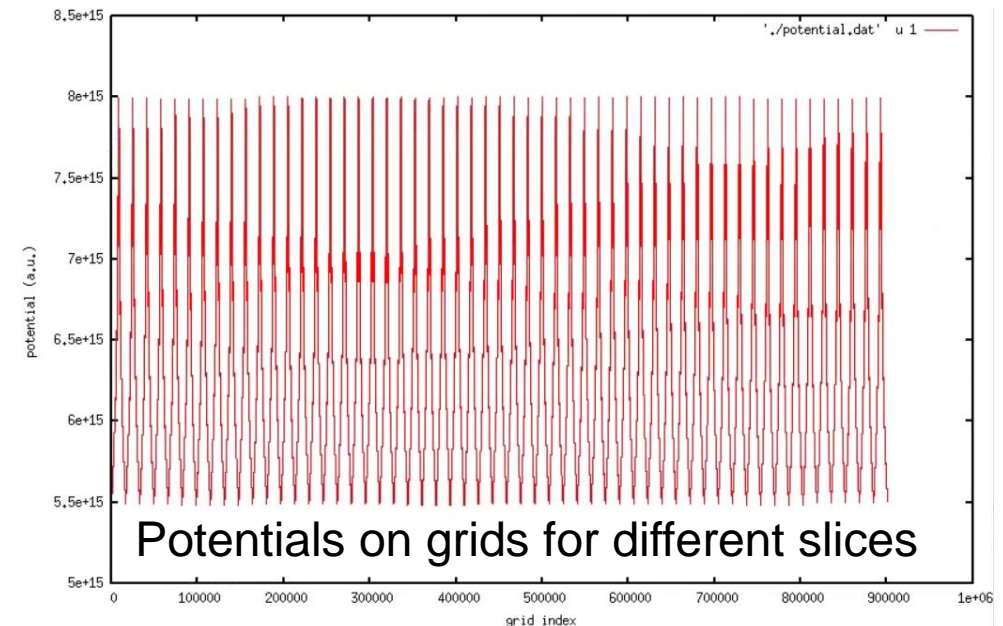
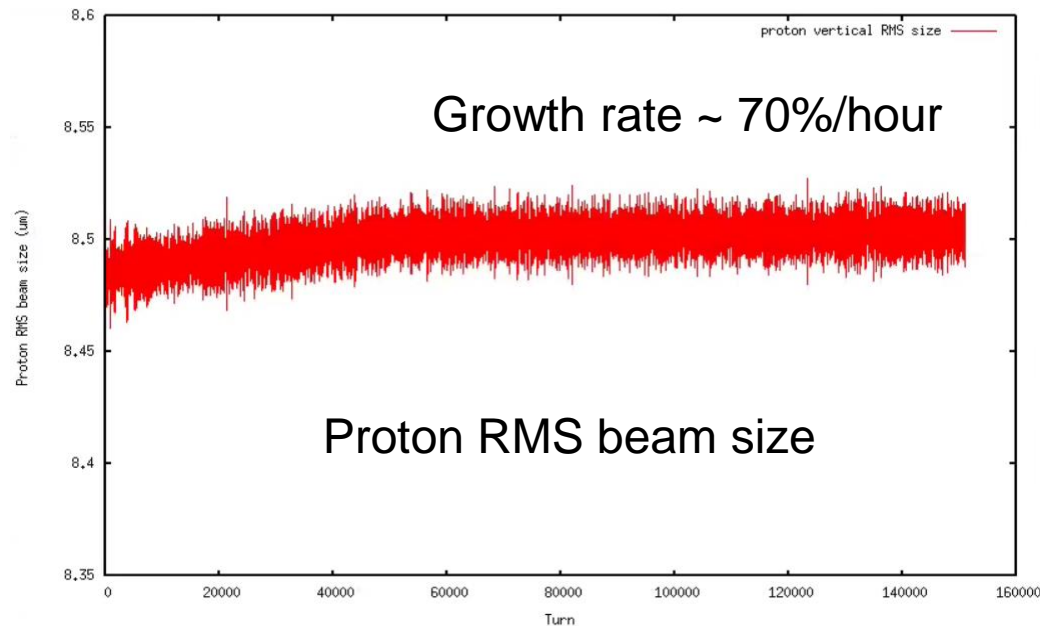
flatness	ID	proton beta*x,y [cm]	proton horizontal growth rate [%/hour]	proton vertical growth rate [%/hour]
0.06	43-47	90/5.4	-0.68+/-1.10	14.57+/-7.1
0.08	33-37	90/7.2	-0.52+/-0.37	2.6 +/--1.9
0.09	49-53	90/8.1	0.16+/-0.94	2.7+/-3.1
0.10	28-32	90/9.0	0.09+/-0.86	1.2+/-2.6
0.12	one seed	90/10.9	0.05	0.87
0.14	59-63	90/12.6	-1.2+/-2.5	0.27+/-8.9
0.09	91-95	80/7.2	0.11+/-0.75	3.3+/-3.2



In weak-strong simulation, electron bunch is rigid with design bunch sizes. 5 electron slices were used. Proton bunch represented by 10k macro-particles and tracked to 2 million turns. Several seeds of initial distribution are used to get a RMS error bar in calculated growth rates.

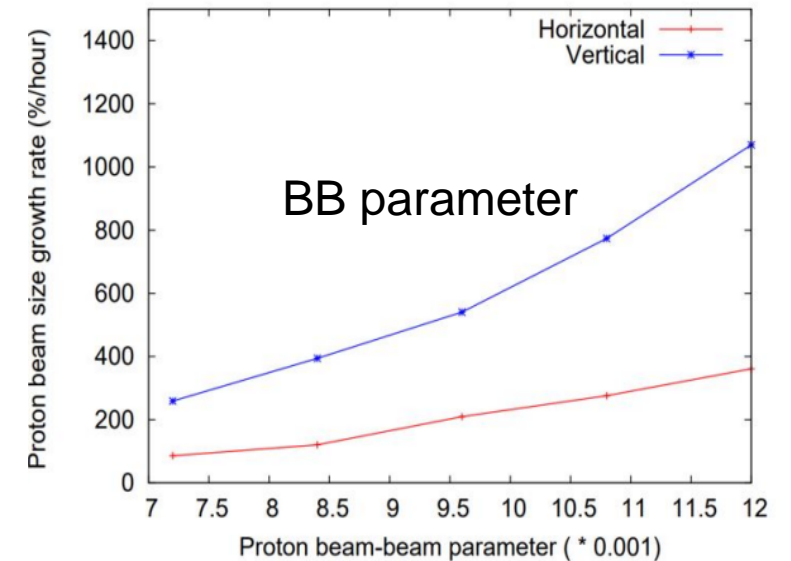
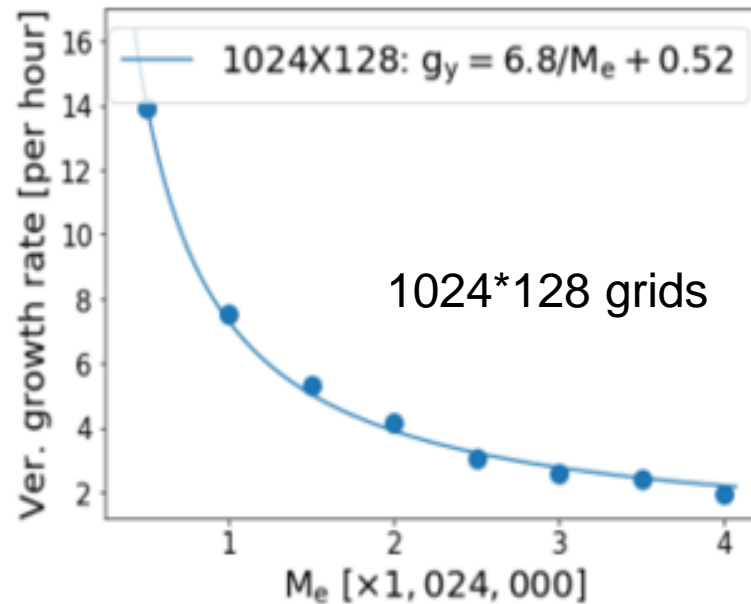
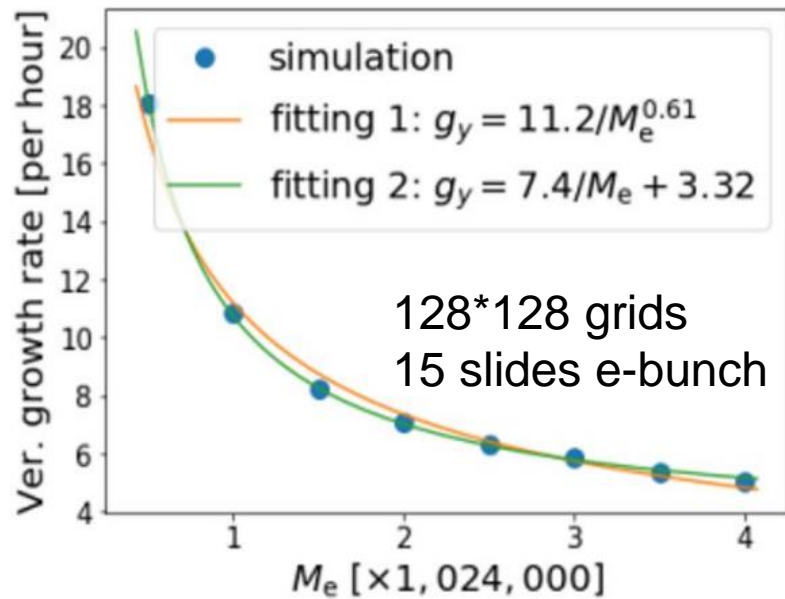
Frozen Model

- After the electron bunch reaches its quasi-equilibrium in a strong-strong simulation, we freeze the electron particle distribution and its space charge potential. Then we do weak-strong simulation with the electron potentials. In the code, potentials are averaged in 1000 turns.
- The proton vertical beam size growth rate from frozen model is between the strong-strong and weak-strong models. Frozen model gets rid of TBT variation but still carries errors in PIC Poisson solver.



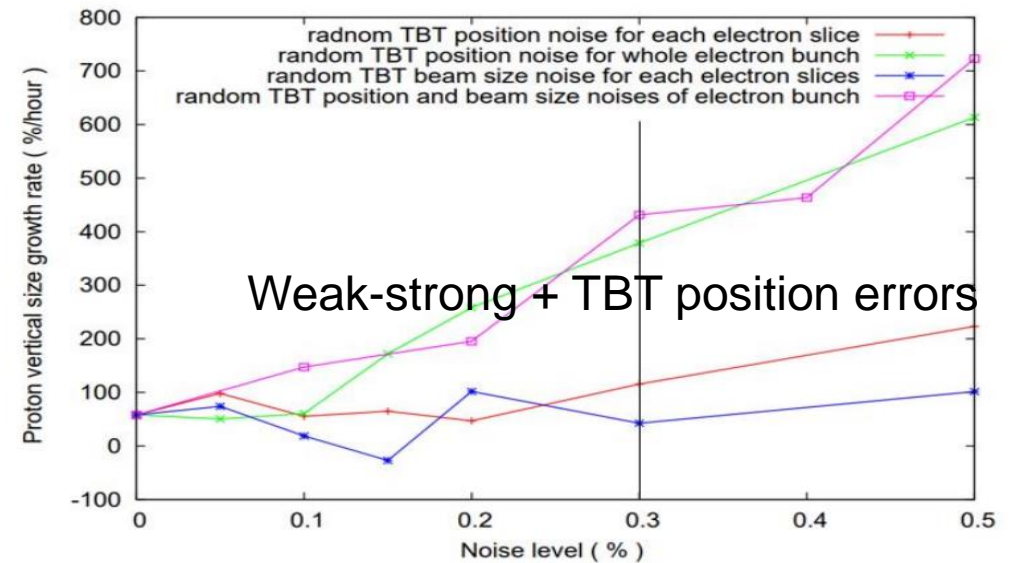
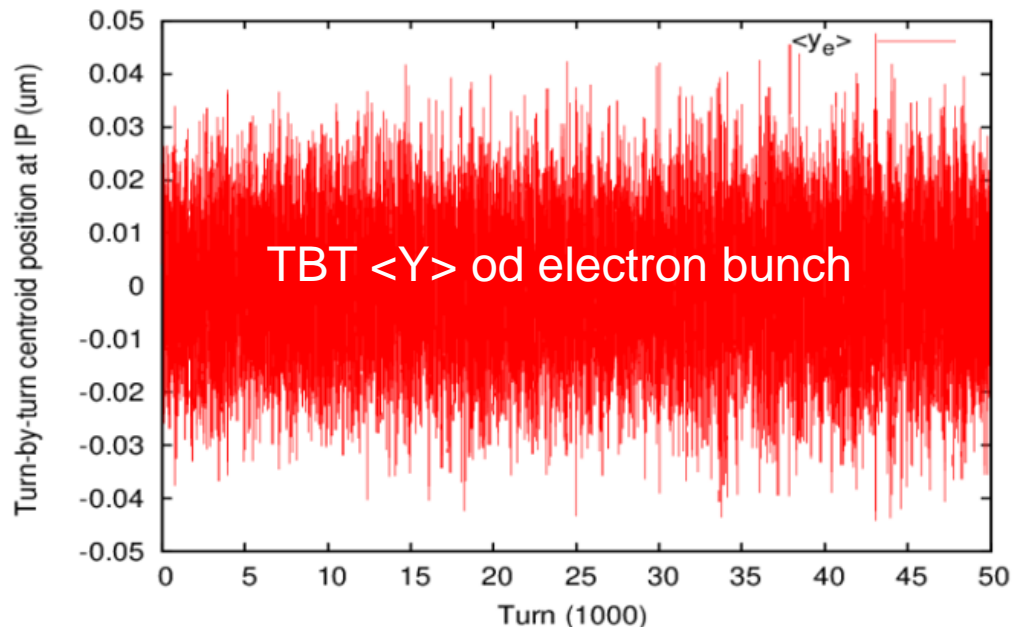
Converging Studies

- Analytically, the numerical noise introduced artificial emittance growth rate in the strong-strong beam-beam simulation **is inversely proportional to the number of macroparticles** and **proportional to the square of the beam-beam parameter**, if beam-beam nonlinear effect is weak enough.
- In EIC strong-strong simulation, the growth rate goes down with increased macro-particles, transverse grids, and longitudinal slices. It also decreases with a smaller BB parameter and with a rounder transverse beam.



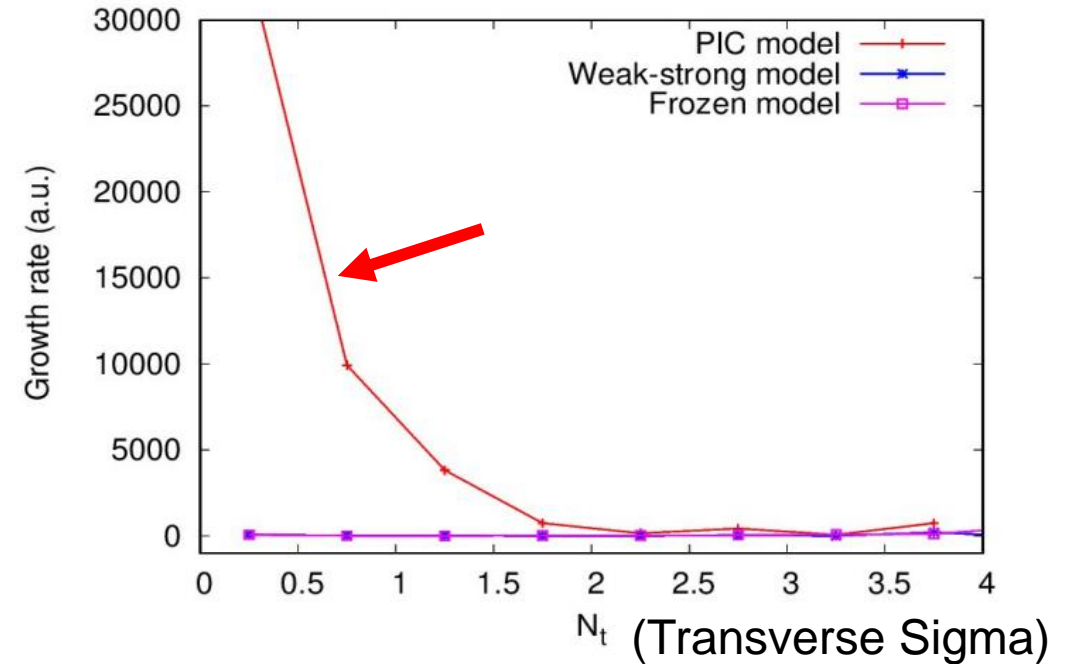
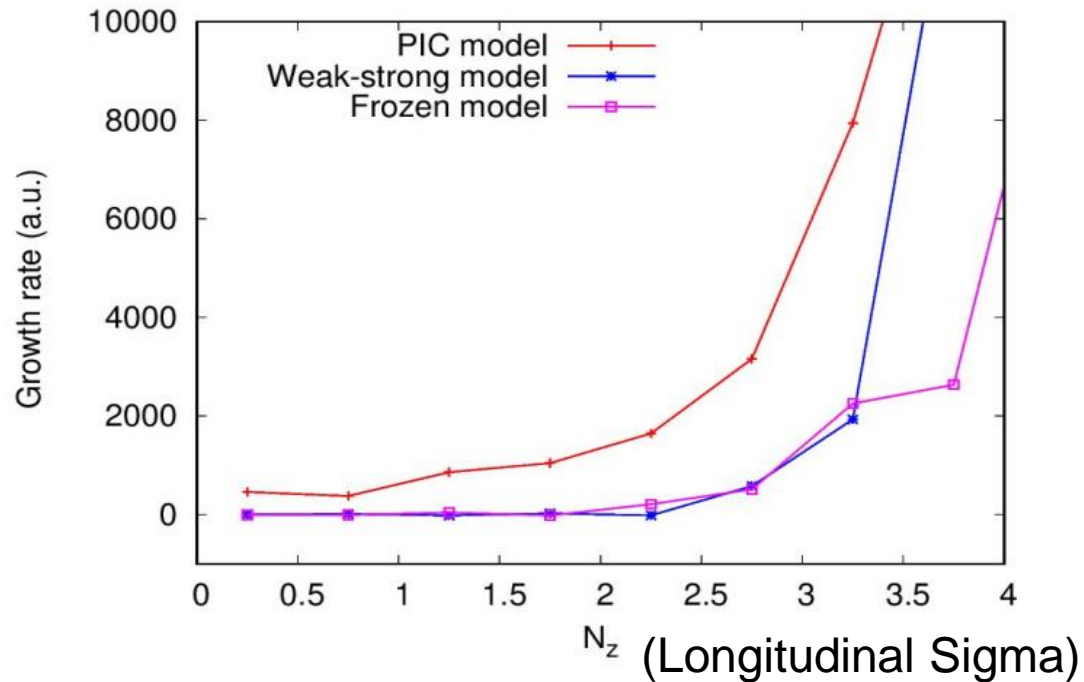
Turn-by-Turn Position and Beam Size Variation

- With typically 0.5 to 1 million macro-particles per bunch, the **RMS variations of electron bunch center and transverse beam sizes are about 0.2-0.3% of their RMS beam sizes at IP.**
- The impact of dipole moment of electron bunch can be eliminated by introducing virtual symmetric macro-particles in the PIC Poisson solver but growth rate doesn't go down much with this trick. **Dipole motion is not the main source for emittance growth.**
- TBT Beam size variation in simulation code is less than 0.2% of 1 sigma, which is not the main source for observed emittance growth either.



Macro-particles Contribute Most Emittance Growth

- To identify which macro-particles contribute most of proton emittance growth rates, we calculate RMS beam size growth rate of macro-particles as function of their initial longitudinal and transverse actions.
- **We found that macro-particles in the transverse bunch core contribute most of the artificial emittance growth rate in the strong-strong beam-beam simulation.**

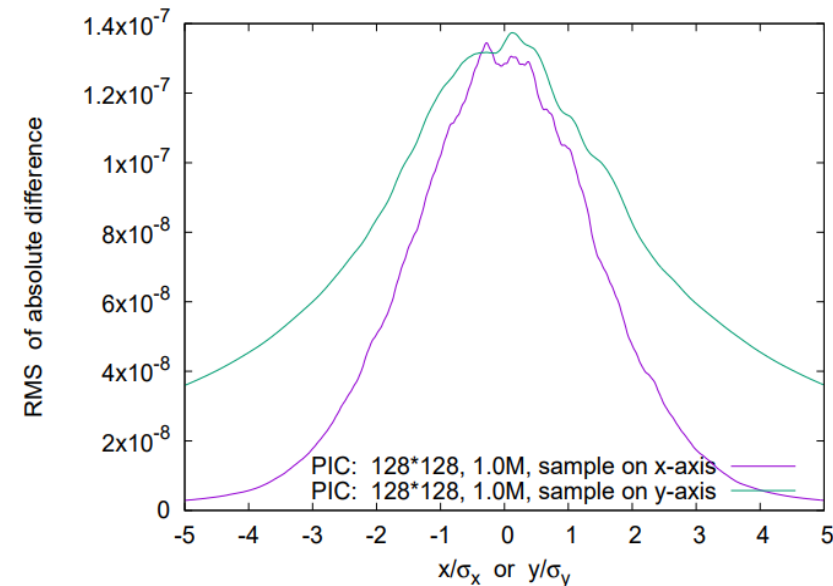
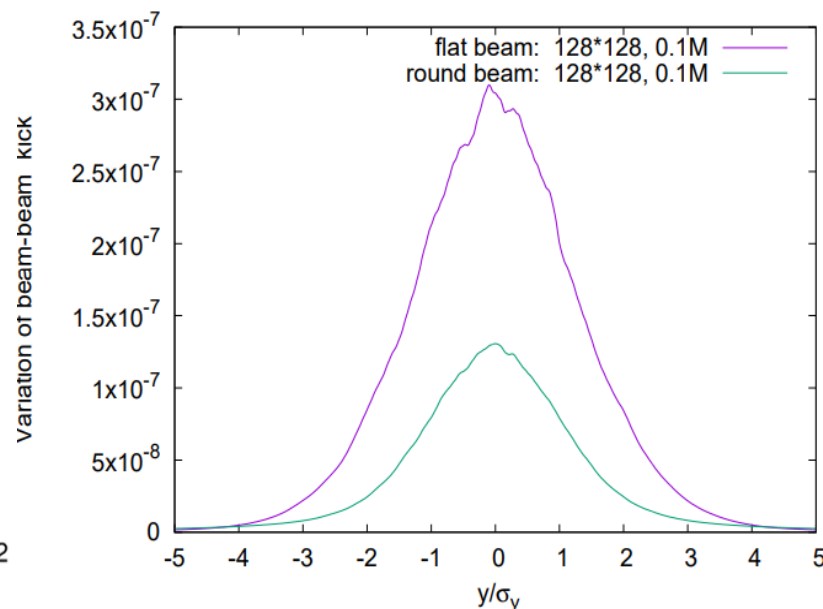
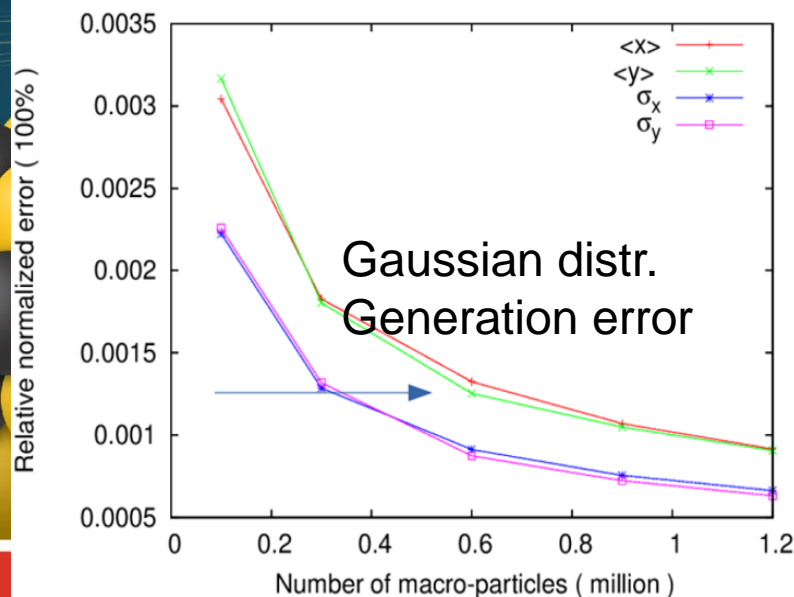


Tests of PIC Based Poisson Solver

- We estimate RMS variation of beam-beam kick from PIC Poisson solver for a given 4-D Gaussian distribution (with same RMS beam sizes) of 1000 particle distributions.
- **We found that PIC based Poisson solver tends to have a larger variation (noise) in BB kick for particles in the bunch core, especially in the vertical plane for a flat beam.**

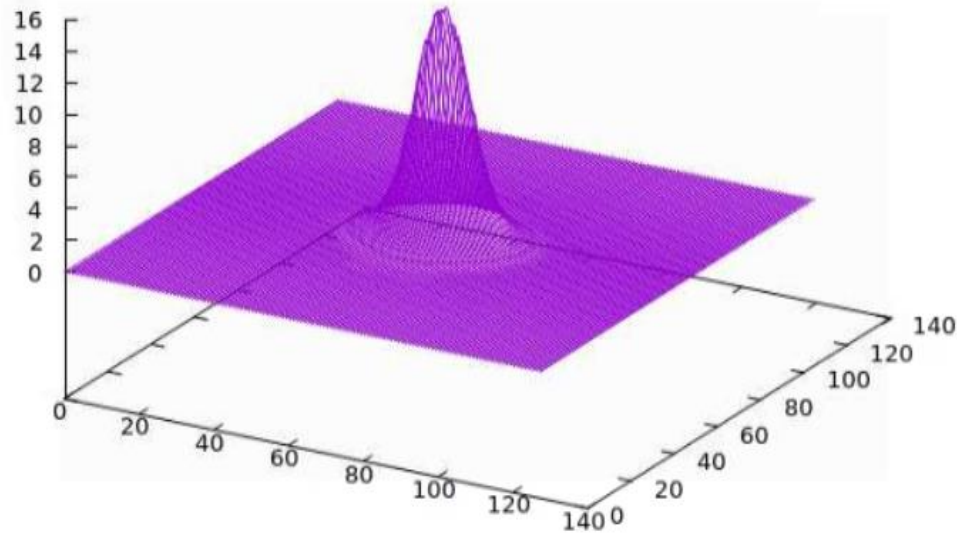
This explained why we observed much faster beam size growth rates for macro-particles in the bunch core in the strong-strong simulation.

Y. Luo, et al, IPAC2022, WEPOPT040.

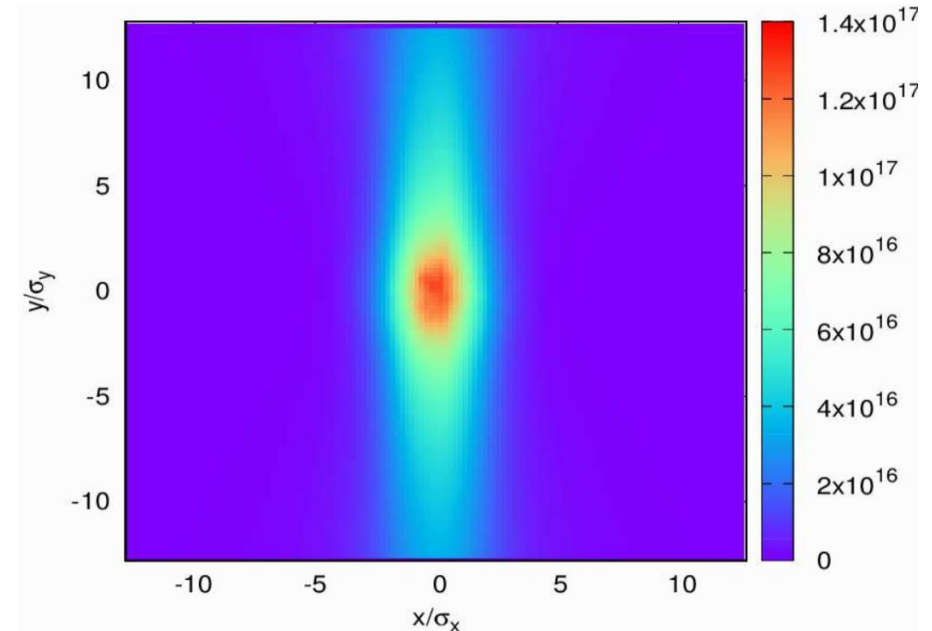


Turn-by-Turn Variation in BB Kicks

We dug into a real strong-strong simulation with $0.5M * 0.5M$ macro-particles each bunch and PIC Poisson solver with $128 * 128$ grids. **1000 turns after equilibrium are used for variation calculation.**



RMS variation of charge density on $128 * 128$ grids.

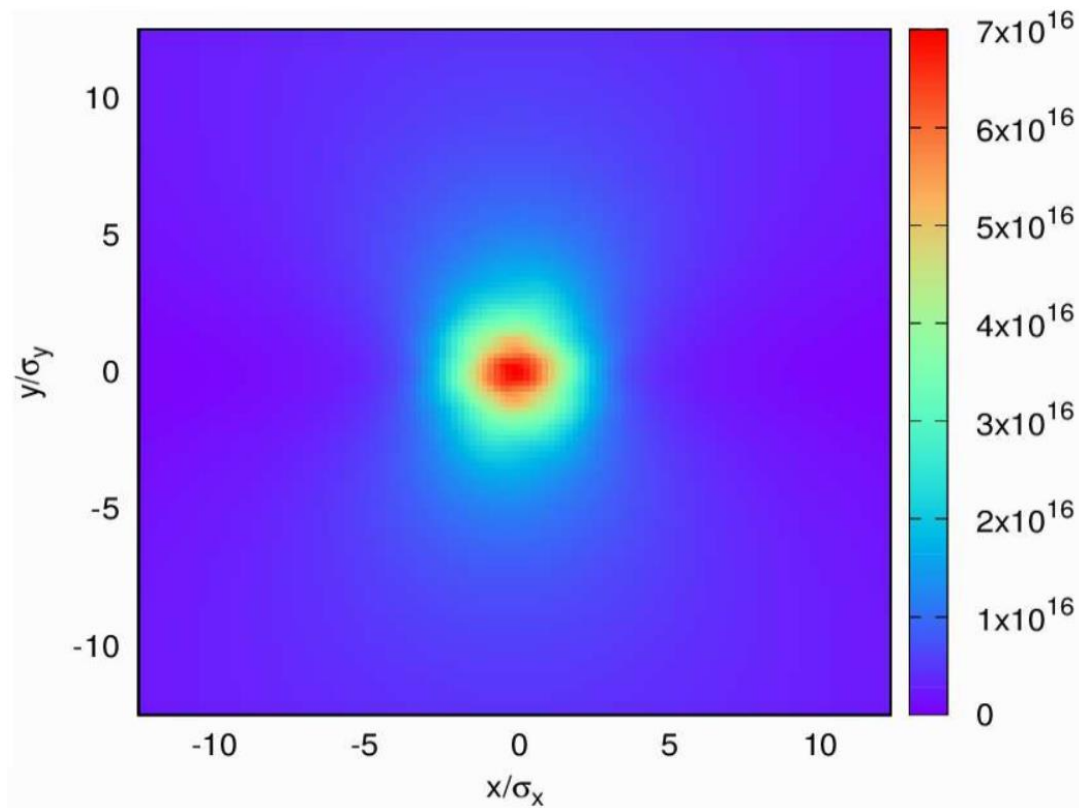


RMS variation of vertical BB kick on grids.

- **We observed larger variations in charge density and BB kick for central area of e-bunch. Also, variation of BB kick goes down slowly in the vertical direction for a flat bunch.**

As a comparison: round beams in RHIC

Vertical BB kick variation

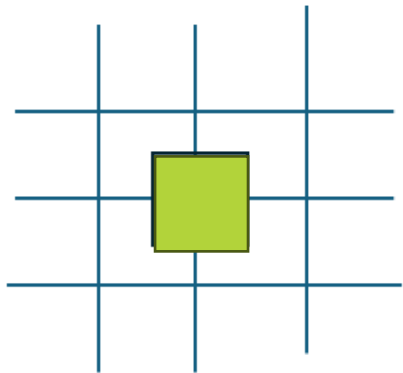


Extracted from a strong-strong BB simulation for RHIC.

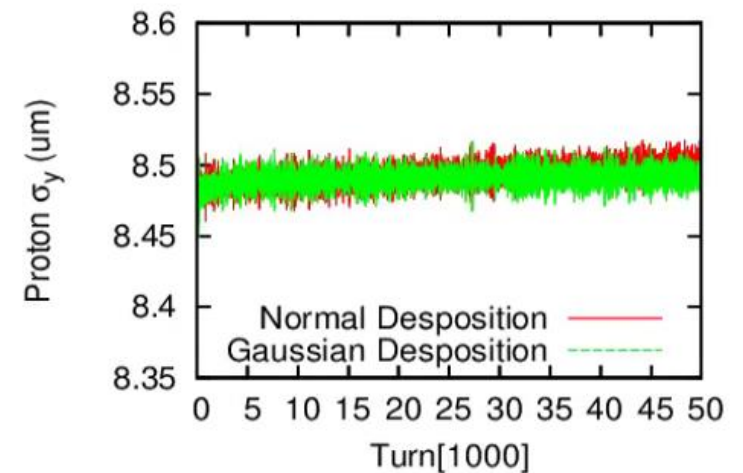
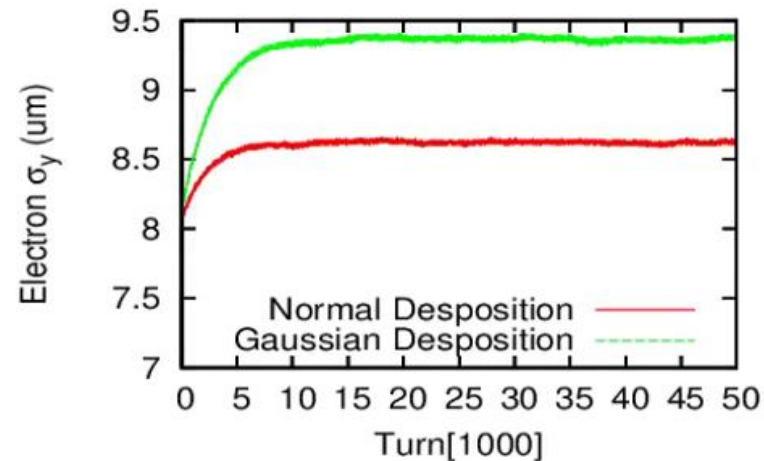
- For a round beam, beam-beam variation has no much difference in horizontal and vertical beam-beam kicks.
- BB kick variation is overall smaller than flat beam.
- We also observed a larger BB force variation for bunch core particles.
- From physics, particles in bunch core is more stable than tail particles. We don't observe emittance growth rates from strong-strong simulation.

Recent Test with Analytical Density Deposition

- At each collision point, we first calculate centers and RMS size of macro-particles in one slice. Then we assign charge onto each grid analytically assuming Gaussian charge distribution. PIC solver and E_x , E_y calculation remain the same as normal strong-strong codes.
- By doing so, we notice that the proton emittance growth rate goes down to $\sim 200\%.$ hour, still far away from the weak-strong growth rate. This method doesn't exclude the TBT variations and electrical field interpolation.



Gaussian charge in the square $\pm 1/2$ grid sizes assigned to the grid



Summary

- Numerical noise can be reduced by greatly increasing macro-particles, transverse grids, and longitudinal slices in PIC solver.
- Turn-by-turn variation of bunch motion can increase proton emittance growth rate but not the main contributor to the artificial emittance growth in strong-strong simulation.
- PIC solver generates a larger numerical variation in beam-beam force calculation for macro-particles in the bunch core.
- It is found with S-S simulation codes that macro-particles near bunch core contribute most of artificial emittance growth in strong-strong simulation.
- Strong-strong beam-beam simulation based on PIC is subject to large numerical noises, therefore it is not suitable for quantitative calculation for emittance growth rates.
- However, strong-strong BB simulation is suitable for design parameter optimization, tune scan, coherent BB motion, fast beam instabilities with wake fields, etc.